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| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|---|-----------------------|----------------------|-----------------------|------------------|
| 10/604,082 | 06/25/2003 | David R. Medeiros | FIS920030159US1 | 1081 |
| | 32074 7590 10/18/2004 | | EXAMINER | |
| INTERNATIONAL BUSINESS MACHINES CORPORATION DEPT. 18G | | | CHACKO DAVIS, DABORAH | |
| BLDG. 300-48 | BLDG. 300-482 | | ART UNIT | PAPER NUMBER |
| 2070 ROUTE 52 HOPEWELL HINCTION MY 12522 | | 1756 | | |

DATE MAILED: 10/18/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

| | Application No. | Applicant(s) | | | | |
|--|---|-------------------------|--|--|--|--|
| | 10/604,082 | MEDEIROS ET AL. | | | | |
| Office Action Summary | Examiner | Art Unit | | | | |
| | Daborah Chacko-Davis | 1756 | | | | |
| The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply | | | | | | |
| A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). | | | | | | |
| Status | | | | | | |
| 1) Responsive to communication(s) filed on <u>25 June 2003</u> . | | | | | | |
| 2a)☐ This action is FINAL . 2b)☒ This action is non-final. | | | | | | |
| 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213. | | | | | | |
| | | | | | | |
| Disposition of Claims | | | | | | |
| 4) Claim(s) 1-19 is/are pending in the application. | | | | | | |
| 4a) Of the above claim(s) is/are withdrawn from consideration. 5) Claim(s) is/are allowed. | | | | | | |
| 6)⊠ Claim(s) <u>1-19</u> is/are rejected. | | | | | | |
| 7) Claim(s) is/are objected to. | | | | | | |
| 8) Claim(s) are subject to restriction and/or election requirement. | | | | | | |
| Application Papers | | | | | | |
| 9)☐ The specification is objected to by the Examiner. | | | | | | |
| 10) The drawing(s) filed on is/are: a) □ accepted or b) □ objected to by the Examiner. | | | | | | |
| | Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). | | | | | |
| Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). | | | | | | |
| 11)☐ The oath or declaration is objected to by the Exa | miner. Note the attached Office | Action or form PTO-152. | | | | |
| Priority under 35 U.S.C. § 119 | | | | | | |
| 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: | | | | | | |
| 1. Certified copies of the priority documents have been received. | | | | | | |
| 2. Certified copies of the priority documents have been received in Application No | | | | | | |
| 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). | | | | | | |
| * See the attached detailed Office action for a list of the certified copies not received. | | | | | | |
| | | | | | | |
| August 1973 | | | | | | |
| Attachment(s) 1) Notice of References Cited (PTO-892) | ∆ □ | 370, 440) | | | | |
| 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) | 4) | ə | | | | |
| 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date <u>06/03</u> . | 5) Notice of Informal Par 6) Other: | | | | | |
| S Patent and Today of Office. | | | | | | |

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DETAILED ACTION

Claim Rejections - 35 USC § 112

- The following is a quotation of the second paragraph of 35 U.S.C. 112:
 The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.
- 2. Claims 6, 8, and 11, are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. Claim 6, at line 2, recites a temperature range of "10-75°C", and claim 8, at line 2, recites a temperature range of "20-50°C". It is not clear if the temperature range is in the absolute scale or the centigrade scale. Appropriate correction is required.
- 3. Claim 6, at lines 1-2, recites the limitation "the thermal processing temperature of step (D)". There is insufficient antecedent basis for this limitation in the claim.
- 4. Claim 8, at lines 1-2, recites the limitation "the thermal processing temperature of step (D)". There is insufficient antecedent basis for this limitation in the claim.
- 5. Claim 11, at lines 1-2, recites the limitation "the thermal processing of step (D)". There is insufficient antecedent basis for this limitation in the claim.

Claim Rejections - 35 USC § 102

6. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the

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applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

7. Claims 1-5, 7, and 9-19, are rejected under 35 U.S.C. 102(e) as being anticipated by U. S. Patent Application Publication No. 2002/0182534 (Varanasi et al).

Varanasi, in the abstract, in paragraphs [0008], [0009], [0010], [0030], [0032], [0045], [0046], [0047], [0056], [0057], [0058], [0059], [0060], [0061], and [0068] discloses a method of forming resist structures to transfer patterns to an underlying layer (material layer) inorder to form features that are less than 130nm in size, wherein the method includes applying a positive resist composition to the desired semiconductor substrate, the resist composition comprises i) an acid sensitive imaging polymer, and ii) a radiation sensitive acid generator, wherein the imaging polymer includes plural acidlabile moieties (PALM groups) that inhibit solubility of the resist in the absence of a generated acid (i.e., low activation energy); the method includes performing a pattern wise-exposure on the resist layer such that acid is generated in the exposed regions of the layer, treating the exposed regions with bulky groups (during exposure or postexposure, bulky deprotection co-reactant product is formed in the resist) so as to promote acid catalyzed reactions (promoting alkaline solubility in acid generated areas, exposed areas) for a sufficient time (avoiding too much shrinkage), developing the exposed resist layer to form a pattern by contacting the resist layer with a developer to remove the exposed areas of the resist, and transferring the pattern of the resist structure to the underlying material layer by reactive ion etching (claims 1, 4, 12-13, and 18). Varanasi, in [0056], discloses that the material layer may be a conductor layer, a

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ceramic layer or a semiconducting layer (claim 2). Varanasi, in [0030], discloses that the acid-labile moiety is either a ketal or an acetal (claims 3, and 17). Varanasi, in [0056], and [0062] discloses an intermediate layer (ARC) between the material layer and the resist layer, such that the pattern is transferred from the patterned resist to the intermediate layer (ARC or hard mask layer) prior to the transfer to the underlying layer (material layer) (claim 5). Varanasi, in [0030], [0031], and [0032], discloses that the deprotection group (bulky group, Q) is present in the imaging polymer during exposure (claim 7). Varanasi, in [0060], discloses that the resist is treated with an aqueous solution (water as the reactant) (claim 9). Varanasi, in [0067], discloses that the exposure is performed in an anhydrous condition (vacuum conditions) (claim 10). Varanasi, in [0059], discloses that the post-exposure baking is performed in atmosphere (not vacuum, inherently humid) (claim 11). Varanasi, in [0058], and [0067], discloses that the exposure was performed at a wavelength of about 193 nm (claim 14). Varanasi, in [0055], discloses that eUV radiations can be employed for performing exposures (claim 15). Varanasi, in [0058], discloses that an electron beam is used to expose the resist layer (claim 16). Varanasi, in [0061], discloses that patterned structure can be used to form metal wiring lines (depositing metal in the spaces between the resist pattern) (claim 19).

Claim Rejections - 35 USC § 103

8. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

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(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

9. Claims 6, and 8, are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent Application Publication No. 2002/0182534 (Varanasi et al) in view of U.S. Patent No. 6,399,273 (Yamada et al).

Varanasi is discussed in paragraph no. 7.

The difference between the claims and Varanasi is that Varanasi does not disclose that the thermal processing temperature is about 10-75°C (as recited in claims 6, and 8).

Yamada, in col 18, lines 60-65, discloses that the heat treatment is performed at a temperature of about 60°C.

Therefore, it would be obvious to a skilled artisan to modify Varanasi by employing the temperature suggested by Yamada during the heat treatment (post exposure heating) because Yamada, in col 4, lines 37-47, discloses that upon heating the exposed resist layer, the unexposed region of the polymer undergoes chemical transformations rendering the unexposed regions of the polymer insoluble to developing solutions.

Conclusion

10. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Daborah Chacko-Davis whose telephone number is (571) 272-1380. The examiner can normally be reached on M-F 9:30 - 6:00. If

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attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Mark F Huff can be reached on (571) 272-1385. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

dcd

September 28, 2004.

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